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April 1st, 2010 Renesas Electronics Corporation

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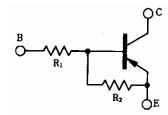


COMPOUND TRANSISTOR HR1 SERIES

on-chip resistor PNP silicon epitaxial transistor For mid-speed switching

FEATURES

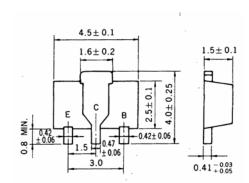
- Up to 2A high current drives such as IC outputs and actuators available
- On-chip bias resistor
- · Low power consumption during drive



HR1 SERIES LISTS

Products	Marking	R ₁ (kΩ)	R ₂ (kΩ)
HR1A3M	MP	1.0	1.0
HR1F3P	MQ	2.2	10
HR1L3N	MR	4.7	10
HR1A4M	MS	10	10
HR1L2Q	MT	0.47	4.7
HR1F2Q	MU	0.22	2.2
HR1A4A	MX	_	10

PACKAGE DRAWING (UNIT: mm)



Electrode Connection

- E. Emitter
- C. Collector
- R. Base

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	-60	V
Collector to emitter voltage	Vceo	-60	V
Emitter to base voltage	V _{EBO}	-10	V
Collector current (DC)	Ic(DC)	-1.0	Α
Collector current (Pulse)	I _{C(pulse)} Note1	-2.0	Α
Base current (DC)	I _{B(DC)}	-0.02	Α
Total power dissipation	P _T Note2	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

Notes 1. PW \leq 10 ms, duty cycle \leq 50 %

2. When $0.7 \text{ mm} \times 16 \text{ cm}^2$ ceramic board is used

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HR1A3M ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	h _{FE1} Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.1 \text{ A}$	50			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V, } I_{C} = -0.5 \text{ A}$	100			_
DC current gain	hFE3 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -1.0 \text{ A}$	50			-
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V, Ic} = -0.4 \text{ A}$			-0.4	V
Low level input voltage	V _{IL} Note	$V_{CE} = -5.0 \text{ V, } I_{C} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R ₁		0.7	1.0	1.3	kΩ
E-to-B resistance	R ₂		0.7	1.0	1.3	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HR1F3P

ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V _{CB} = -60 V, I _E = 0			-100	nA
DC current gain	h _{FE1} Note	Vce = -2.0 V, Ic = -0.1 A	150			
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			ı
DC current gain	h _{FE3} Note	$V_{CE} = -2.0 \text{ V, Ic} = -1.0 \text{ A}$	50			-
Low level output voltage	V _{OL} Note	$V_{IN} = -5.0 \text{ V}, \text{ Ic} = -0.3 \text{ A}$			-0.3	٧
Low level input voltage	V _{IL} Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	٧
Input resistance	R ₁		1.54	2.2	2.86	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HR1L3N

ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	Vcb = -60 V, IE = 0			-100	nA
DC current gain	h _{FE1} Note	Vce = -2.0 V, Ic = -0.1 A	150			Ī
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			-
DC current gain	hFE3 Note	Vce = −2.0 V, lc = −1.0 A	50			_
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V}, \text{ Ic} = -0.2 \text{ A}$			-0.3	V
Low level input voltage	VIL Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R ₁		3.29	4.7	6.11	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

2



HR1A4M ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	h _{FE1} Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.1 \text{ A}$	150			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			_
DC current gain	h _{FE3} Note	$V_{CE} = -2.0 \text{ V, Ic} = -1.0 \text{ A}$	50			-
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V, Ic} = -0.1 \text{ A}$			-0.2	V
Low level input voltage	V _{IL} Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R ₁		7	10	13	kΩ
E-to-B resistance	R ₂		7	10	13	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HR1L2Q ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	h _{FE1} Note	$V_{CE} = -2.0 \text{ V}, I_{C} = -0.1 \text{ A}$	150			_
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			
DC current gain	h _{FE3} Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -1.0 \text{ A}$	50			-
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$			-0.55	V
Low level input voltage	V _{IL} Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R ₁		329	470	611	Ω
E-to-B resistance	R ₂		3.29	4.7	6.11	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

HR1F2Q ELECTRICAL CHARACTERISTICS (TA = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	hFE1 Note	$V_{CE} = -2.0 \text{ V, Ic} = -0.1 \text{ A}$	100			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$	100			-
DC current gain	h _{FE3} Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -1.0 \text{ A}$	50			_
Low level output voltage	Vol. Note	$V_{IN} = -5.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$			-0.55	V
Low level input voltage	V _{IL} Note	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -100 \ \mu\text{A}$			-0.3	V
Input resistance	R ₁		154	220	286	Ω
E-to-B resistance	R ₂		1.54	2.2	2.86	kΩ

Note PW \leq 350 μ s, duty cycle \leq 2 %

Data Sheet D16184EJ4V0DS



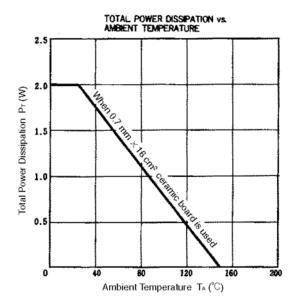
HR1A4A ELECTRICAL CHARACTERISTICS (T_A = 25°C)

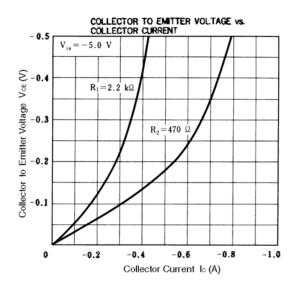
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, I_E = 0$			-100	nA
DC current gain	hFE1 Note	$V_{CE} = -2.0 \text{ V, Ic} = -0.1 \text{ A}$	150			-
DC current gain	hFE2 Note	$V_{CE} = -2.0 \text{ V}, I_{C} = -0.5 \text{ A}$	100			_
DC current gain	hfE3 Note	$V_{CE} = -2.0 \text{ V, Ic} = -1.0 \text{ A}$	50			-
Collector saturation voltage	V _{CE(sat)} Note	$Ic = -500 \text{ mA}, I_B = -10 \text{ mA}$		0.20	0.35	V
Low level input voltage	V _{IL} Note	$V_{CE} = -5.0 \text{ V, Ic} = -100 \ \mu\text{A}$	-0.3		-1.5	V
E-to-B resistance	R ₂		7	10	13	kΩ

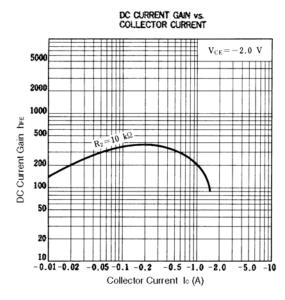
Note PW \leq 350 μ s, duty cycle \leq 2 %

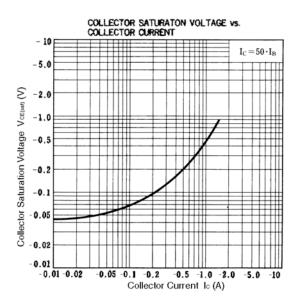


<R> TYPICAL CHARACTERISTICS (TA = 25°C)









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